



MM54HC181/MM74HC181

Arithmetic Logic Units/Function Generators

General Description

These arithmetic logic units (ALU)/function generators utilize advanced silicon-gate CMOS technology. They possess the high noise immunity and low power consumption of standard CMOS integrated circuits, as well as the ability to drive 10 LS-TTL loads.

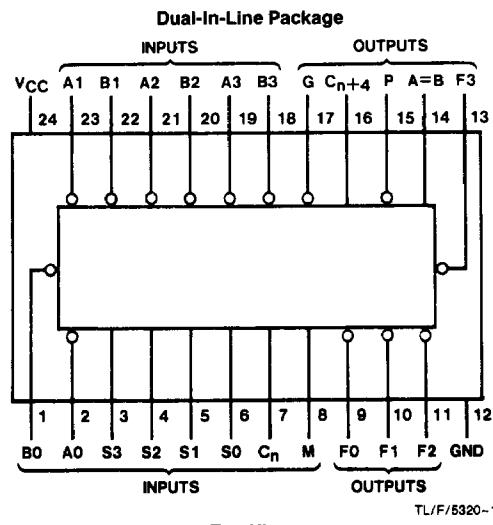
The MM54HC181/MM74HC181 are arithmetic logic unit (ALU)/function generators that have a complexity of 75 equivalent gates on a monolithic chip. These circuits perform 16 binary arithmetic operations on two 4-bit words as shown in Tables 1 and 2. These operations are selected by the four function-select lines (S_0, S_1, S_2, S_3) and include addition, subtraction, decrement, and straight transfer. When performing arithmetic manipulations, the internal carries must be enabled by applying a low-level voltage to the mode control input (M). A full carry look-ahead scheme is made available in these devices for fast, simultaneous carry generation by means of two cascade-outputs (pins 15 and 17) for the four bits in the package. When used in conjunction with the MM54HC182 or MM74HC182, full carry look-ahead circuits, high-speed arithmetic operations can be performed. The method of cascading HC182 circuits with these ALU's to provide multi-level full carry look-ahead is illustrated under typical applications data for the MM54HC182/MM74HC182.

If high speed is not of importance, a ripple-carry input (C_n) and a ripple-carry output (C_{n+4}) are available. However, the ripple-carry delay has also been minimized so that arithmetic manipulations for small word lengths can be performed without external circuitry.

Features

- Full look-ahead for high-speed operations on long words
- Arithmetic operating modes:
 - Addition
 - Subtraction
 - Shift operand and one position magnitude comparison
 - Plus twelve other arithmetic operations
- Logic function modes:
 - Exclusive-OR
 - Comparator
 - AND, NAND, OR, NOR
 - Plus ten other logic operations
- Wide operating voltage range: 2V–6V
- Low input current: 1 μ A maximum
- Low quiescent current: 80 μ A maximum

Connection Diagram



Pin Designations

Designation	Pin Nos.	Function
A3, A2, A1, A0	19, 21, 23, 2	Word A Inputs
B3, B2, B1, B0	18, 20, 22, 1	Word B Inputs
S3, S2, S1, S0	3, 4, 5, 6	Function-Select Inputs
C _n	7	Inv. Carry Input
M	8	Mode Control Input
F3, F2, F1, F0	13, 11, 10, 9	Function Outputs
A = B	14	Comparator Outputs
P	15	Carry Propagate Output
C _{n+4}	16	Inv. Carry Output
G	17	Carry Generate Output
V _{CC}	24	Supply Voltage
GND	12	Ground

Order Number MM54HC181* or MM74HC181*

*Please look into Section 8, Appendix D
for availability of various package types.

General Description (Continued)

These circuits will accommodate active-high or active-low data, if the pin designations are interpreted as shown below. Subtraction is accomplished by 1's complement addition where the 1's complement of the subtrahend is generated internally. The resultant output is $A - B - 1$, which requires an end-around or forced carry to produce $A - B$.

The 181 can also be utilized as a comparator. The $A = B$ output is internally decoded from the function outputs (F_0, F_1, F_2, F_3) so that when two words of equal magnitude are applied at the A and B inputs, it will assume a high level to indicate equality ($A = B$). The ALU should be in the subtract mode with $C_n = H$ when performing this comparison. The $A = B$ output is open-drain so that it can be wire-AND connected to give a comparison for more than four bits. The carry output (C_{n+4}) can also be used to supply relative magnitude information. Again, the ALU should be placed in the subtract mode by placing the function select inputs S_3, S_2, S_1, S_0 at L, H, H, L, respectively.

These circuits have been designed to not only incorporate all of the designer's requirements for arithmetic operations,

but also to provide 16 possible functions of two Boolean variables without the use of external circuitry. These logic functions are selected by use of the four function-select inputs (S_0, S_1, S_2, S_3) with the mode-control input (M) at a high level to disable the internal carry. The 16 logic functions are detailed in Tables 1 and 2 and include exclusive-OR, NAND, AND, NOR, and OR functions.

ALU SIGNAL DESIGNATIONS

The MM54HC181/MM74HC181 can be used with the signal designations of either Figure 1 or Figure 2.

The logic functions and arithmetic operations obtained with signal designations as in Figure 1 are given in Table 1; those obtained with the signal designations of Figure 2 are given in Table 2.

The 54HC/74HC logic family is speed, function, and pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Pin Number	2	1	23	22	21	20	19	18	9	10	11	13	7	16	15	17
Active-High Data (Table 1)	A0	B0	A1	B1	A2	B2	A3	B3	F0	F1	F2	F3	\bar{C}_n	C_{n+4}	X	Y
Active-Low Data (Table 1)	$\bar{A}0$	$\bar{B}0$	$\bar{A}1$	$\bar{B}1$	$\bar{A}2$	$\bar{B}2$	$\bar{A}3$	$\bar{B}3$	$\bar{F}0$	$\bar{F}1$	$\bar{F}2$	$\bar{F}3$	C_n	C_{n+4}	\bar{P}	\bar{G}

Input C_n	Output C_{n+4}	Active-High Data (Figure 1)	Active-Low Data (Figure 2)
H	H	$A \leq B$	$A \geq B$
H	L	$A > B$	$A < B$
L	H	$A < B$	$A > B$
L	L	$A \geq B$	$A \leq B$

Table I

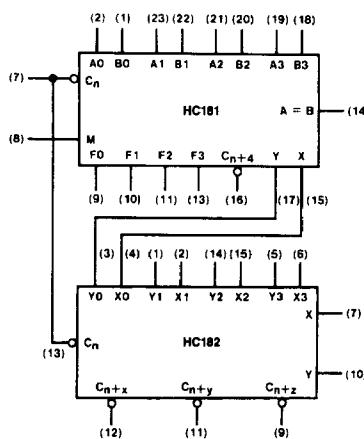
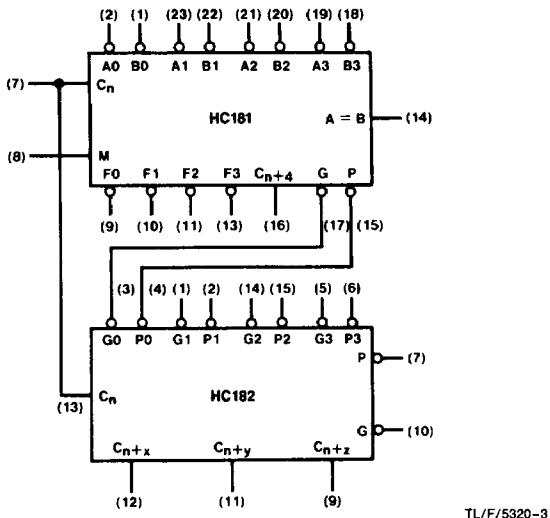


FIGURE 1

Selection	Active High Data				
	M = H Logic Functions		M = L; Arithmetic Operations		
S3	S2	S1	S0	$C_n = H$ (no carry)	$C_n = L$ (with carry)
L	L	L	L	$F = \bar{A}$	$F = A$
L	L	L	H	$F = A + \bar{B}$	$F = (A + B) \text{ Plus } 1$
L	L	H	L	$F = \bar{A}\bar{B}$	$F = A + \bar{B}$
L	L	H	H	$F = 0$	$F = \text{Minus } 1 \text{ (2's Compl)}$
L	H	L	L	$F = \bar{A}\bar{B}$	$F = A \text{ Plus } \bar{A}\bar{B}$
L	H	L	H	$F = \bar{B}$	$F = (A + B) \text{ Plus } AB$
L	H	H	L	$F = A \oplus B$	$F = A \text{ Minus } B \text{ Minus } 1$
L	H	H	H	$F = \bar{A}\bar{B}$	$F = \bar{A}\bar{B} \text{ Minus } 1$
H	L	L	L	$F = \bar{A} + B$	$F = A \text{ Plus } AB$
H	L	L	H	$F = A \oplus B$	$F = A \text{ Plus } B$
H	L	H	L	$F = B$	$F = (A + \bar{B}) \text{ Plus } AB$
H	L	H	H	$F = AB$	$F = AB \text{ Minus } 1$
H	H	L	L	$F = 1$	$F = A \text{ Plus } A^*$
H	H	L	H	$F = A + \bar{B}$	$F = (A + B) \text{ Plus } A$
H	H	H	L	$F = A + B$	$F = (A + \bar{B}) \text{ Plus } A$
H	H	H	H	$F = A$	$F = A \text{ Minus } 1$

*Each bit is shifted to the next more significant position.

General Description (Continued)



TL/F/5320-3

FIGURE 2

Table II

Selection				Active Low Data		
				M = H Logic Functions	M = L; Arithmetic Operations	
S3	S2	S1	S0		C _n = L (no carry)	C _n = H (with carry)
L	L	L	L	F = \bar{A}	F = A Minus 1	F = A
L	L	L	H	F = $\bar{A}\bar{B}$	F = AB Minus 1	F = AB
L	L	H	L	F = $\bar{A} + B$	F = $\bar{A}\bar{B}$ Minus 1	F = ($\bar{A}\bar{B}$)
L	L	H	H	F = 1	F = Minus 1 (2's Compl)	F = Zero
L	H	L	L	F = $A + \bar{B}$	F = A Plus (A + \bar{B})	F = A Plus (A + \bar{B}) Plus 1
L	H	L	H	F = \bar{B}	F = AB Plus (A + B)	F = AB Plus (A + \bar{B}) Plus 1
L	H	H	L	F = $\bar{A} + \bar{B}$	F = A Minus B Minus 1	F = A Minus B
L	H	H	H	F = $A + \bar{B}$	F = A + \bar{B}	F = (A + \bar{B}) Plus 1
H	L	L	L	F = $\bar{A}\bar{B}$	F = A Plus (A + B)	F = A Plus (A + B) Plus 1
H	L	L	H	F = A + B	F = A Plus B	F = A Plus B Plus 1
H	L	H	L	F = B	F = $\bar{A}\bar{B}$ Plus (A + B)	F = $\bar{A}\bar{B}$ Plus (A + B) Plus 1
H	L	H	H	F = A + B	F = A + B	F = (A + B) Plus 1
H	H	L	L	F = 0	F = A Plus A*	F = A Plus A Plus 1
H	H	L	H	F = $\bar{A}\bar{B}$	F = AB Plus A	F = AB Plus A Plus 1
H	H	H	L	F = AB	F = $\bar{A}\bar{B}$ Plus A	F = $\bar{A}\bar{B}$ Plus A Plus 1
H	H	H	H	F = A	F = A	F = A Plus 1

*Each bit is shifted to the next more significant position.

Number of Bits	Typical Addition Times	Package Count		Carry Method Between ALU's
		Arithmetic/ Logic Units	Look Ahead Carry Generators	
1 to 4	20 ns	1	0	None
5 to 8	30 ns	2	0	Ripple
9 to 16	30 ns	3 or 4	1	Full Look-Ahead
17 to 64	50 ns	5 to 16	2 to 5	Full Look-Ahead

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	-0.5 to $+7.0$ V
DC Input Voltage (V_{IN})	-1.5 to $V_{CC} + 1.5$ V
DC Output Voltage (V_{OUT})	-0.5 to $V_{CC} + 0.5$ V
Clamp Diode Current (I_{IK}, I_{OK})	± 20 mA
DC Output Current, per pin (I_{OUT})	± 25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	± 50 mA
Storage Temperature Range (T_{STG})	-65°C to $+150^{\circ}\text{C}$
Power Dissipation (P_D) (Note 3) S.O. Package only	600 mW 500 mW
Lead Temperature (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	-40	$+85$	°C
MM54HC	-55	$+125$	°C
Input Rise or Fall Times (t_r, t_f)			
$V_{CC} = 2.0$ V		1000	ns
$V_{CC} = 4.5$ V		500	ns
$V_{CC} = 6.0$ V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25^{\circ}\text{C}$		74HC $T_A = -40$ to 85°C	54HC $T_A = -55$ to 125°C	Units
				Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage		2.0V 4.5V 6.0V	1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V
V_{IL}	Maximum Low Level Input Voltage**		2.0V 4.5V 6.0V	0.5 1.35 1.8	0.5 1.35 1.8	0.5 1.35 1.8	0.5 1.35 1.8	V
V_{OH}	Minimum High Level Output Voltage (any output except A=B)	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 20 \mu\text{A}$	2.0V 4.5V 6.0V	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0 \text{ mA}$ $ I_{OUT} \leq 5.2 \text{ mA}$	4.5V 6.0V	4.2 5.7	3.98 5.48	3.84 5.34	3.7 5.2	V
I_{LKG}	Maximum Leakage Open Drain Output Current (A = B Output)	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$	6.0V		0.5	5.0	10	μA
V_{OL}	Maximum Low Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 20 \mu\text{A}$	2.0V 4.5V 6.0V	0 0 0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0 \text{ mA}$ $ I_{OUT} \leq 5.2 \text{ mA}$	4.5V 6.0V	0.2 0.2	0.26 0.26	0.33 0.33	0.4 0.4	V
I_{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0V		± 0.1	± 1.0	± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu\text{A}$	6.0V		8.0	80	160	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: $-12 \text{ mW}/^{\circ}\text{C}$ from 65°C to 85°C ; ceramic "J" package: $-12 \text{ mW}/^{\circ}\text{C}$ from 100°C to 125°C .

Note 4: For a power supply of $5\text{V} \pm 10\%$ the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5$ V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{LKG} , I_{CC} , and I_{OL}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

** V_{IL} limits are currently tested at 20% of V_{CC} . The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

AC Electrical Characteristics $V_{CC} = 5V$, $T_A = 25^\circ C$, $C_L = 15 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL}, t_{PLH}	Maximum Propagation Delay from C_n to C_{n+4}		13	20	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to $C_N + 4$	$M=0V, S_0=S_3=V_{CC}$ $S_1=S_2=0V$ (Sum mode)	30	45	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to $C_N + 4$	$M=0V, S_0=S_3=0V$ $S_1=S_2=V_{CC}$ (Diff. mode)	30	45	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from C_n to any F	$M=0V$ (Sum or Diff. mode)	20	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to G	$M=0V, S_0=S_3=V_{CC}$ $S_1=S_2=0V$ (Sum mode)	20	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to G	$M=0V, S_0=S_3=0V$ $S_1=S_2=V_{CC}$ (Diff mode)	20	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to P	$M=0V, S_0=S_3=V_{CC}$ $S_1=S_2=0V$ (Sum mode)	27	41	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to P	$M=0V, S_0=S_3=0V$ $S_1=S_2=V_{CC}$ (Diff mode)	24	37	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from A_I or B_I to F_I	$M=0V, S_0=S_3=V_{CC}$ $S_1=S_2=0V$ (Sum mode)	20	30	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from A_I or B_I to F_I	$M=0V, S_0=S_3=0V$ $S_1=S_2=V_{CC}$ (Diff mode)	19	29	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from A_I or B_I to F_I	$M=V_{CC}$ (Logic mode)	25	37	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay from any A or B to $A=B$	$M=0V, S_0=S_3=0V$ $S_1=S_2=V_{CC}$ (Diff mode)	25	37	ns

AC Electrical Characteristics $C_L = 50 \text{ pF}$, $t_r = t_f = 6 \text{ ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		74HC	54HC	Units
				Typ		T _A = -40 to 85°C	T _A = -55 to 125°C	
t _{PHL} , t _{PLH}	Maximum Propagation Delay from C _n to C _{n+4}		2.0V 4.5V 6.0V		125 25 22	155 31 28	190 38 33	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to C _{n+4}	M = 0V, S ₀ = S ₃ = V _{CC} S ₁ = S ₂ = 0V (Sum mode)	2.0V 4.5V 6.0V	110 35 30	250 50 43	325 63 53	375 75 65	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to C _{n+4}	M = 0V, S ₀ = S ₃ = 0V S ₁ = S ₂ = V _{CC} (Diff mode)	2.0V 4.5V 6.0V		250 50 43	325 63 53	375 75 65	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from C _n to any F	M = 0V (Sum or Diff mode)	2.0V 4.5V 6.0V	65 22 14	150 32 28	190 40 35	225 48 42	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to G	M = 0V, S ₀ = S ₃ = V _{CC} , S ₁ = S ₂ = 0V (Sum mode)	2.0V 4.5V 6.0V	70 20 12	175 35 30	220 44 38	263 53 45	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to G	M = 0V, S ₀ = S ₃ = 0V S ₁ = S ₂ = 0V (Diff mode)	2.0V 4.5V 6.0V	65 23 16	165 33 29	210 42 37	250 50 44	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to P	M = 0V, S ₀ = S ₃ = V _{CC} S ₁ = S ₂ = 0V (Sum mode)	2.0V 4.5V 6.0V	80 30 25	220 44 37	275 55 47	330 66 56	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to P	M = 0V, S ₀ = S ₃ = 0V S ₁ = S ₂ = V _{CC} (Diff mode)	2.0V 4.5V 6.0V	75 27 24	195 39 34	244 49 43	293 60 51	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from A _I or B _I to F _I	M = 0V, S ₀ = S ₃ = V _{CC} S ₁ = S ₂ = 0V (Sum mode)	2.0V 4.5V 6.0V	70 26 21	180 36 31	225 45 39	270 54 47	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from A _I or B _I to F _I	M = 0V, S ₀ = S ₃ = 0V S ₁ = S ₂ = V _{CC} (Diff mode)	2.0V 4.5V 6.0V		160 32 27	200 40 34	290 48 41	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from A _I or B _I to F _I	M = V _{CC} (Logic mode)	2.0V 4.5V 6.0V	180 30 23	200 40 34	250 50 43	300 60 51	ns ns ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from any A or B to A = B	M = 0V, S ₀ = S ₃ = 0V S ₁ = S ₂ = V _{CC} (Diff mode)	2.0V 4.5V 6.0V	180 30 23	200 40 34	250 50 43	300 60 51	ns ns ns
t _{TLH} , t _{THL}	Maximum Output Rise and Fall Time		2.0V 4.5V 6.0V	30 8 7	75 15 13	95 19 16	110 22 19	ns ns ns
C _{PD}	Power Dissipation Capacitance (Note 5)			300				pF
C _{IN}	Maximum Input Capacitance			5	15	15	15	pF

Note 5: C_{PD} determines the no load dynamic power consumption, P_D = C_{PD} V_{CC}² f + I_{CC} V_{CC}, and the no load dynamic current consumption, I_S = C_{PD} V_{CC} f + I_{CC}.

Parameter Measurement Information**Logic Mode Test Table**Function Inputs: $S_1 = S_2 = M = V_{CC}$, $S_0 = S_3 = 0\text{ V}$

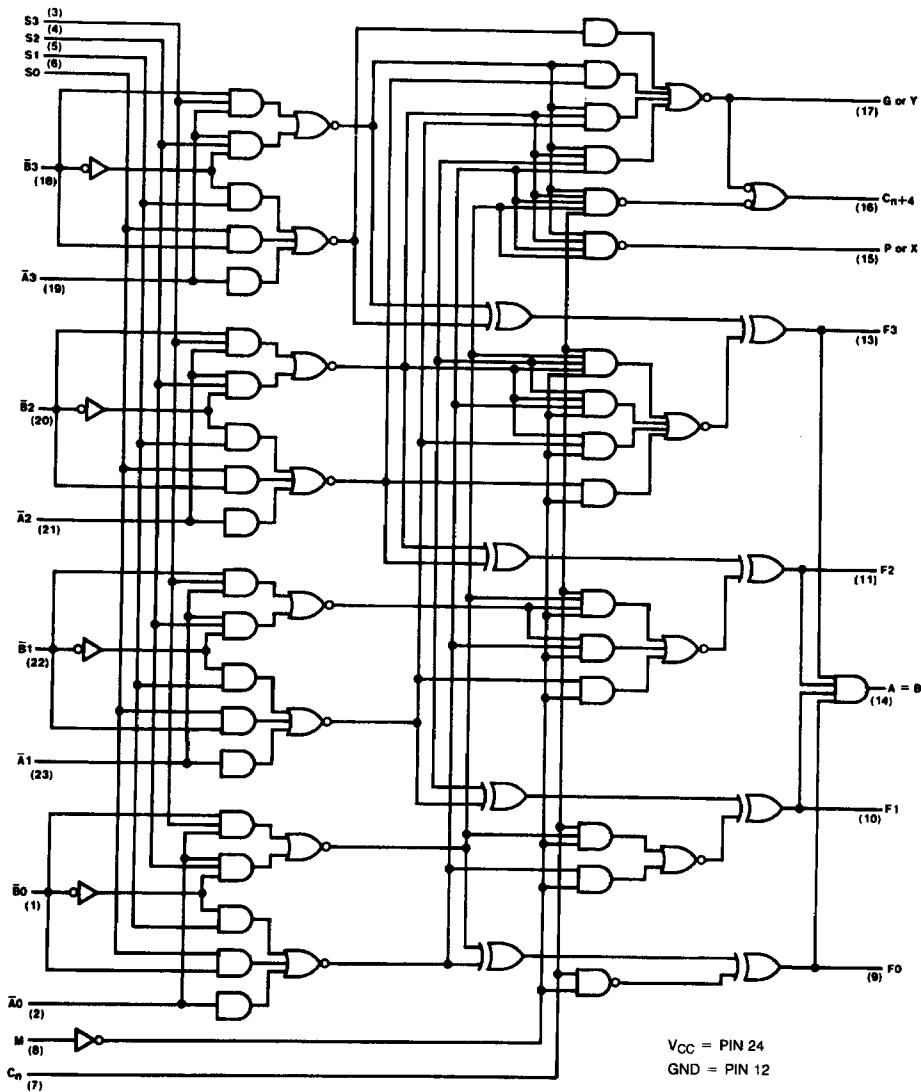
Parameter	Input Under Test	Other Input Same Bit		Other Data Inputs		Output Under Test	Output Waveform
		Apply V_{CC}	Apply GND	Apply V_{CC}	Apply GND		
t_{PHL}, t_{PLH}	A _I	B _I	None	None	Remaining A and B, C _n	F _I	Out-of-Phase
t_{PHL}, t_{PLH}	B _I	A _I	None	None	Remaining A and B, C _n	F _I	Out-of-Phase

SUM Mode Test TableFunction Inputs: $S_0 = S_3 = V_{CC}$ $S_1 = S_2 = M = 0\text{ V}$

Parameter	Input Under Test	Other Input Same Bit		Other Data Inputs		Output Under Test	Output Waveform
		Apply V_{CC}	Apply GND	Apply V_{CC}	Apply GND		
t_{PHL}, t_{PLH}	A _I	B _I	None	Remaining A and B	C _n	F _I	In-Phase
t_{PHL}, t_{PLH}	B _I	A _I	None	Remaining A and B	C _n	F _I	In-Phase
t_{PHL}, t_{PLH}	A _I	B _I	None	None	Remaining A and B, C _n	P	In-Phase
t_{PHL}, t_{PLH}	B _I	A _I	None	None	Remaining A and B, C _n	P	In-Phase
t_{PHL}, t_{PLH}	A _I	None	B _I	Remaining B	Remaining A, C _n	G	In-Phase
t_{PHL}, t_{PLH}	B _I	None	A _I	Remaining B	Remaining A, C _n	G	In-Phase
t_{PHL}, t_{PLH}	C _n	None	None	All A	All B	Any F or C _{n+4}	In-Phase
t_{PHL}, t_{PLH}	A _I	None	B _I	Remaining B	Remaining A, C _n	C _{n+4}	Out-of-Phase
t_{PHL}, t_{PLH}	B _I	None	A _I	Remaining B	Remaining A, C _n	C _{n+4}	Out-of-Phase

Diff Mode Test TableFunction Inputs: $S_1 = S_2 = V_{CC}$, $S_0 = S_3 = M = 0\text{ V}$

Parameter	Input Under Test	Other Input Same Bit		Other Data Inputs		Output Under Test	Output Waveform
		Apply V_{CC}	Apply GND	Apply V_{CC}	Apply GND		
t_{PHL}, t_{PLH}	A _I	None	B _I	Remaining A	Remaining B, C _n	F _I	In-Phase
t_{PHL}, t_{PLH}	B _I	A _I	None	Remaining A	Remaining B, C _n	F _I	Out-of-Phase
t_{PHL}, t_{PLH}	A _I	None	B _I	None	Remaining A and B, C _n	P	In-Phase
t_{PHL}, t_{PLH}	B _I	A _I	None	None	Remaining A and B, C _n	P	Out-of-Phase
t_{PHL}, t_{PLH}	A _I	B _I	None	None	Remaining A and B, C _n	G	In-Phase
t_{PHL}, t_{PLH}	B _I	None	A _I	None	Remaining A and B, C _n	G	Out-of-Phase
t_{PHL}, t_{PLH}	A _I	None	B _I	Remaining A	Remaining B, C _n	A=B	In-Phase
t_{PHL}, t_{PLH}	B _I	A _I	None	Remaining A	Remaining B, C _n	A=B	Out-of-Phase
t_{PHL}, t_{PLH}	C _n	None	None	All A and B	None	C _{n+4} or any F	In-Phase
t_{PHL}, t_{PLH}	A _I	B _I	None	None	Remaining A, B, C _n	C _{n+4}	Out-of-Phase
t_{PHL}, t_{PLH}	B _I	None	A _I	None	Remaining A, B, C _n	C _{n+4}	In-Phase

Logic Diagram

V_{CC} = PIN 24
 GND = PIN 12

TL/F/5320-4